## CPU Supervisor with 16Kbit SPI EEPROM

Description

These devices combine four popular functions, Power-on Reset Control, Watchdog Timer, Supply Voltage Supervision, and Block Lock Protect Serial EEPROM Memory in one package. This combination lowers system cost, reduces board space requirements, and increases reliability.

Applying power to the device activates the power-on reset circuit which holds $\overline{RESET}$/RESET active for a period of time. This allows the power supply and oscillator to stabilize before the processor can execute code.

The Watchdog Timer provides an independent protection mechanism for microcontrollers. When the microcontroller fails to restart a timer within a selectable time out interval, the device activates the $\overline{RESET}$/RESET signal. The user selects the interval from three preset values. Once selected, the interval does not change, even after cycling the power.

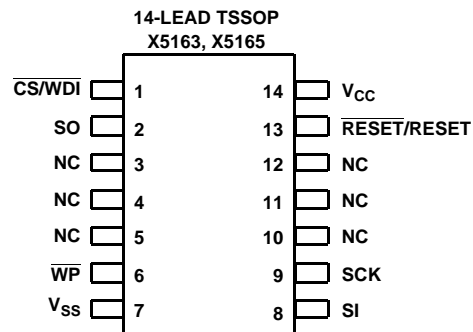The device's low V_{CC} detection circuitry protects the user's system from low voltage conditions, resetting the system when V_{CC} falls below the minimum V_{CC} trip point. $\overline{RESET}$/RESET is asserted until V_{CC} returns to proper operating level and stabilizes. Five industry standard V_{TRIP} thresholds are available, however, Intersil's unique circuits allow the threshold to be reprogrammed to meet custom requirements or to fine-tune the threshold for applications requiring higher precision.
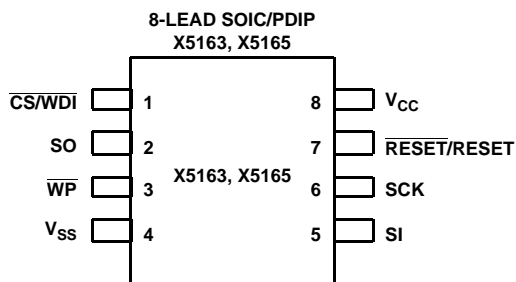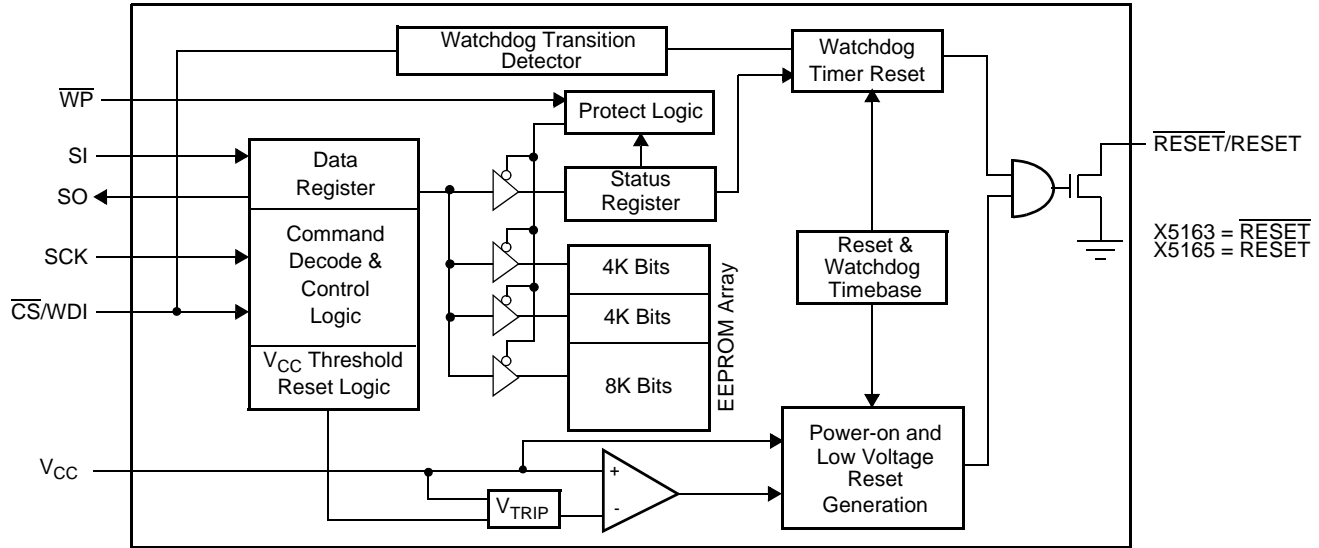
Features

- Selectable watchdog timer
- Low V_{CC} detection and reset assertion
  - Five standard reset threshold voltages
  - Re-program low V_{CC} reset threshold voltage using special programming sequence
  - Reset signal valid to V_{CC} = 1V
- Determine watchdog or low voltage reset with a volatile flag bit
- Long battery life with low power consumption
  - <50µA max standby current, watchdog on
  - <1µA max standby current, watchdog off
  - <400µA max active current during read
- 16Kbits of EEPROM
- Built-in inadvertent write protection
  - Power-up/power-down protection circuitry
  - Protect 0, 1/4, 1/2 or all of EEPROM array with Block Lock™ protection
  - In circuit programmable ROM mode
- 2MHz SPI interface modes (0,0 & 1,1)
- Minimize EEPROM programming time
  - 32-byte page write mode
  - Self-timed write cycle
  - 5ms write cycle time (typical)
- 2.7V to 5.5V and 4.5V to 5.5V power supply operation
- Available packages
  - 14-lead TSSOP, 8-lead SOIC

Pinouts

8-LEAD SOIC/PDIP
X5163, X5165

Pin	Signal		Pin	Signal
1	$\overline{CS}$/WDI		8	V_{CC}
2	SO		7	$\overline{RESET}$/RESET
3	$\overline{WP}$		6	SCK
4	V_{SS}		5	SI

X5163, X5165

14-LEAD TSSOP
X5163, X5165

Pin	Signal		Pin	Signal
1	$\overline{CS}$/WDI		14	V_{CC}
2	SO		13	$\overline{RESET}$/RESET
3	NC		12	NC
4	NC		11	NC
5	NC		10	NC
6	$\overline{WP}$		9	SCK
7	V_{SS}		8	SI

Block Diagram

Pin Description

PIN (SOIC/PDIP)	PIN TSSOP	NAME	FUNCTION
1	1	CS/WDI	**Chip Select Input.** $\overline{CS}$ HIGH, deselects the device and the SO output pin is at a high impedance state. Unless a nonvolatile write cycle is underway, the device will be in the standby power mode. $\overline{CS}$ LOW enables the device, placing it in the active power mode. Prior to the start of any operation after power-up, a HIGH to LOW transition on $\overline{CS}$ is required **Watchdog Input.** A HIGH to LOW transition on the WDI pin restarts the Watchdog timer. The absence of a HIGH to LOW transition within the watchdog time out period results in $\overline{RESET}$/RESET going active.
2	2	SO	**Serial Output.** SO is a push/pull serial data output pin. A read cycle shifts data out on this pin. The falling edge of the serial clock (SCK) clocks the data out.
3	6	WP	**Write Protect.** The $\overline{WP}$ pin works in conjunction with a nonvolatile WPEN bit to "lock" the setting of the Watchdog Timer control and the memory write protect bits.
4	7	V_{SS}	Ground
5	8	SI	**Serial Input.** SI is a serial data input pin. Input all opcodes, byte addresses, and memory data on this pin. The rising edge of the serial clock (SCK) latches the input data. Send all opcodes (Table 1), addresses and data MSB first.
6	9	SCK	**Serial Clock.** The Serial Clock controls the serial bus timing for data input and output. The rising edge of SCK latches in the opcode, address, or data bits present on the SI pin. The falling edge of SCK changes the data output on the SO pin.
7	13	$\overline{RESET}$/RESET	**Reset Output**. $\overline{RESET}$/RESET is an active LOW/HIGH, open drain output which goes active whenever V_{CC} falls below the minimum V_{CC} sense level. It will remain active until V_{CC} rises above the minimum V_{CC} sense level for 200ms. $\overline{RESET}$/RESET goes active if the Watchdog Timer is enabled and $\overline{CS}$ remains either HIGH or LOW longer than the selectable Watchdog time out period. A falling edge of $\overline{CS}$ will reset the Watchdog Timer. $\overline{RESET}$/RESET goes active on power-up at 1V and remains active for 200ms after the power supply stabilizes.
8	14	V_{CC}	Supply Voltage
	3-5,10-12	NC	No internal connections

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Principles Of Operation

Power-on Reset

Application of power to the X516, /X5165 activates a Power-on Reset Circuit. This circuit goes active at 1V and pulls the $\overline{RESET}$/RESET pin active. This signal prevents the system microprocessor from starting to operate with insufficient voltage or prior to stabilization of the oscillator. When V_{CC} exceeds the device V_{TRIP} value for 200ms (nominal) the circuit releases $\overline{RESET}$/RESET, allowing the processor to begin executing code.

Low Voltage Monitoring

During operation, the X5163, X5165 monitors the V_{CC} level and asserts RESET/$\overline{RESET}$ if supply voltage falls below a preset minimum V_{TRIP}. The RESET/RESET signal prevents the microprocessor from operating in a power fail or brownout condition. The RESET/RESET signal remains active until the voltage drops below 1V. It also remains active until V_{CC} returns and exceeds V_{TRIP} for 200ms.

Watchdog Timer

The Watchdog Timer circuit monitors the microprocessor activity by monitoring the WDI input. The microprocessor must toggle the $\overline{CS}$/WDI pin periodically to prevent a $\overline{RESET}$/RESET signal. The $\overline{CS}$/WDI pin must be toggled from HIGH to LOW prior to the expiration of the watchdog time out period. The state of two nonvolatile control bits in the Status Register determine the watchdog timer period. The microprocessor can change these watchdog bits, or they may be "locked" by tying the $\overline{WP}$ pin LOW and setting the WPEN bit HIGH.

V_{CC} Threshold Reset Procedure

The X5163, X5165 has a standard V_{CC} threshold (V_{TRIP}) voltage. This value will not change over normal operating and storage conditions. However, in applications where the standard V_{TRIP} is not exactly right, or for higher precision in the V_{TRIP} value, the X5163, X5165 threshold may be adjusted.

Setting the V_{TRIP} Voltage

This procedure sets the V_{TRIP} to a higher voltage value. For example, if the current V_{TRIP} is 4.4V and the new V_{TRIP} is 4.6V, this procedure directly makes the change. If the new setting is lower than the current setting, then it is necessary to reset the trip point before setting the new value.

To set the new V_{TRIP} voltage, apply the desired V_{TRIP} threshold to the V_{CC} pin and tie the $\overline{CS}$/WDI pin and the $\overline{WP}$ pin HIGH. $\overline{RESET}$ and SO pins are left unconnected. Then apply the programming voltage V_P to both SCK and SI and pulse $\overline{CS}$/WDI LOW then HIGH. Remove V_P and the sequence is complete.
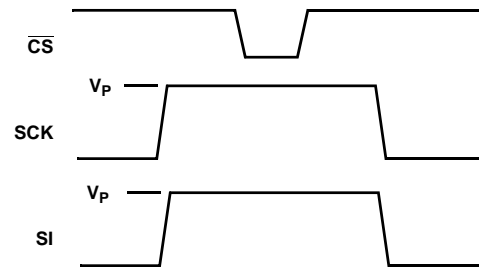

FIGURE 1. SET V_{TRIP} VOLTAGE

Resetting the V_{TRIP} Voltage

This procedure sets the V_{TRIP} to a "native" voltage level. For example, if the current V_{TRIP} is 4.4V and the V_{TRIP} is reset, the new V_{TRIP} is something less than 1.7V. This procedure must be used to set the voltage to a lower value.

To reset the V_{TRIP} voltage, apply a voltage between 2.7 and 5.5V to the V_{CC} pin. Tie the $\overline{CS}$/WDI pin, the $\overline{WP}$ pin, AND THE SCK pin HIGH. $\overline{RESET}$ and SO pins are left unconnected. Then apply the programming voltage V_P to the SI pin ONLY and pulse $\overline{CS}$/WDI LOW then HIGH. Remove V_P and the sequence is complete.
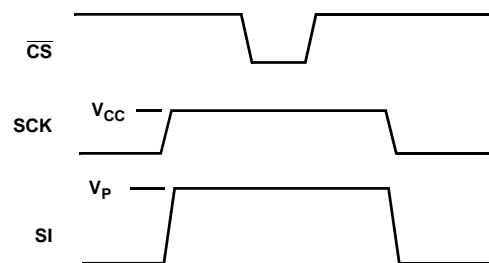

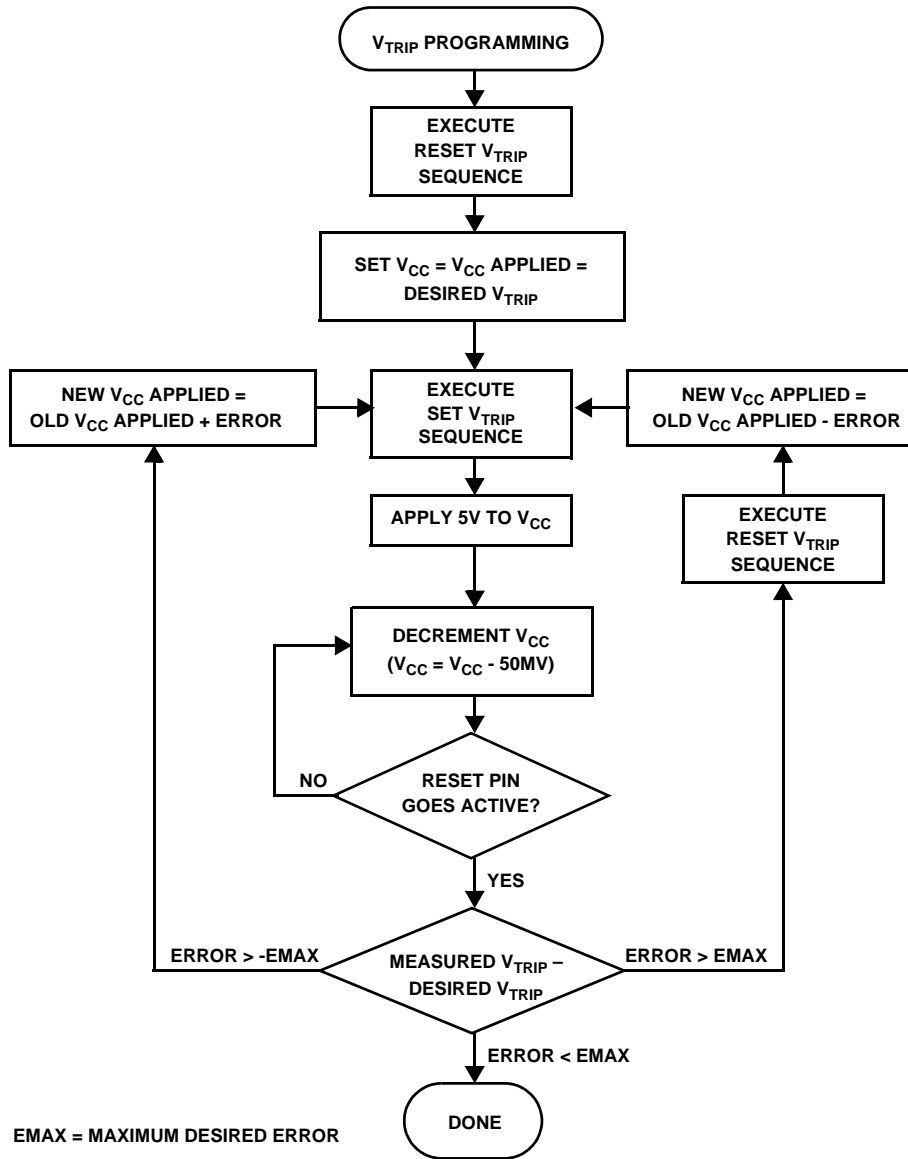**FIGURE 2. RESET V_{TRIP} VOLTAGE**

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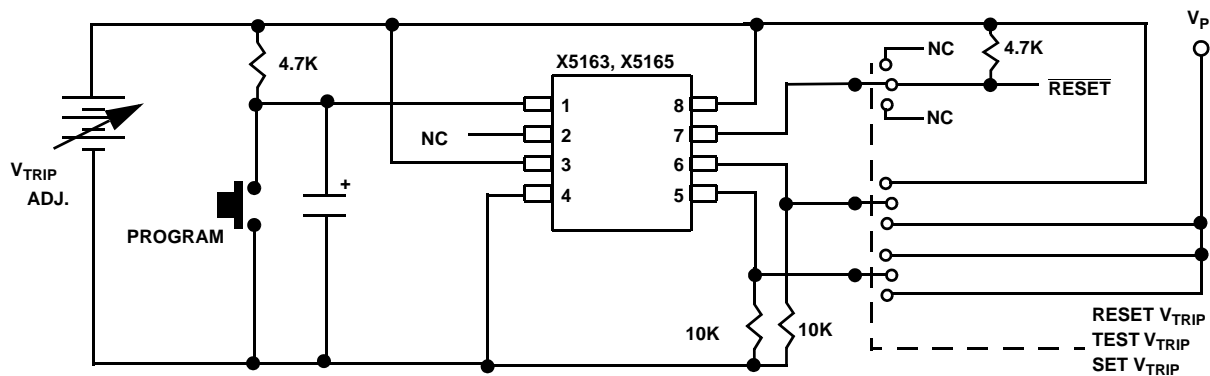FIGURE 3. V$_{TRIP}$ PROGRAMMING SEQUENCE FLOW CHART

FIGURE 4. SAMPLE V$_{TRIP}$ RESET CIRCUIT

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SPI Serial Memory

The memory portion of the device is a CMOS Serial EEPROM array with Intersil's block lock protection. The array is internally organized as x 8. The device features a Serial Peripheral Interface (SPI) and software protocol allowing operation on a simple four-wire bus.

The device utilizes Intersil's proprietary Direct Write™ cell, providing a minimum endurance of 100,000 cycles and a minimum data retention of 100 years.

The device is designed to interface directly with the synchronous Serial Peripheral Interface (SPI) of many popular microcontroller families. It contains an 8-bit instruction register that is accessed via the SI input, with data being clocked in on the rising edge of SCK. CS must be LOW during the entire operation.

All instructions (Table 1), addresses and data are transferred MSB first. Data input on the SI line is latched on the first rising edge of SCK after CS goes LOW. Data is output on the SO line by the falling edge of SCK. SCK is static, allowing the user to stop the clock and then start it again to resume operations where left off.

Write Enable Latch

The device contains a Write Enable Latch. This latch must be SET before a Write Operation is initiated. The WREN instruction will set the latch and the WRDI instruction will reset the latch (Figure 7). This latch is automatically reset upon a power-up condition and after the completion of a valid Write Cycle.

Status Register

The RDSR instruction provides access to the Status Register. The Status Register may be read at any time, even during a Write Cycle. The Status Register is formatted as follows:

7	6	5	4	3	2	1	0
WPEN	FLB	WD1	WD0	BL1	BL0	WEL	WIP

The Write-In-Progress (WIP) bit is a volatile, read only bit and indicates whether the device is busy with an internal nonvolatile write operation. The WIP bit is read using the RDSR instruction. When set to a "1", a nonvolatile write operation is in progress. When set to a "0", no write is in progress.

TABLE 1. INSTRUCTION SET

INSTRUCTION NAME	INSTRUCTION FORMAT*	OPERATION
WREN	0000 0110	Set the Write Enable Latch (Enable Write Operations)
SFLB	0000 0000	Set Flag Bit
WRDI/RFLB	0000 0100	Reset the Write Enable Latch/Reset Flag Bit
RSDR	0000 0101	Read Status Register
WRSR	0000 0001	Write Status Register(Watchdog,BlockLock,WPEN & Flag Bits)
READ	0000 0011	Read Data from Memory Array Beginning at Selected Address
WRITE	0000 0010	Write Data to Memory Array Beginning at Selected Address

NOTE: *Instructions are shown MSB in leftmost position. Instructions are transferred MSB first.

TABLE 2. BLOCK PROTECT MATRIX

WREN CMD	STATUS REGISTER	DEVICE PIN	BLOCK	BLOCK	STATUS REGISTER
WEL	WPEN	WP#	PROTECTED BLOCK	UNPROTECTED BLOCK	WPEN, BL0, BL1, WD0, WD1
0	X	X	Protected	Protected	Protected
1	1	0	Protected	Writable	Protected
1	0	X	Protected	Writable	Writable
1	X	1	Protected	Writable	Writable

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The Write Enable Latch (WEL) bit indicates the Status of the Write Enable Latch. When WEL = 1, the latch is set HIGH and when WEL = 0 the latch is reset LOW. The WEL bit is a volatile, read only bit. It can be set by the WREN instruction and can be reset by the WRDS instruction.

The block lock bits, BL0 and BL1, set the level of block lock protection. These nonvolatile bits are programmed using the WRSR instruction and allow the user to protect one quarter, one half, all or none of the EEPROM array. Any portion of the array that is block lock protected can be read but not written. It will remain protected until the BL bits are altered to disable block lock protection of that portion of memory.

STATUS REGISTER BITS		ARRAY ADDRESSES PROTECTED
BL1	BL0	X516X
0	0	None
0	1	$0600-$07FF
1	0	$0400-$07FF
1	1	$0000-$07FF

The Watchdog Timer bits, WD0 and WD1, select the Watchdog Time Out Period. These nonvolatile bits are programmed with the WRSR instruction.

STATUS REGISTER BITS		WATCHDOG TIME OUT (TYPICAL)
WD1	WD0	
0	0	1.4 seconds
0	1	600 milliseconds

STATUS REGISTER BITS		WATCHDOG TIME OUT (TYPICAL)
WD1	WD0	
1	0	200 milliseconds
1	1	disabled

The FLAG bit shows the status of a volatile latch that can be set and reset by the system using the SFLB and RFLB instructions. The Flag bit is automatically reset upon power-up. This flag can be used by the system to determine whether a reset occurs as a result of a watchdog time out or power failure.

The nonvolatile WPEN bit is programmed using the WRSR instruction. This bit works in conjunction with the $\overline{WP}$ pin to provide an In-Circuit Programmable ROM function (Table 2). $\overline{WP}$ is LOW and WPEN bit programmed HIGH disables all Status Register Write Operations.

In Circuit Programmable ROM Mode

This mechanism protects the block lock and Watchdog bits from inadvertent corruption.

In the locked state (Programmable ROM Mode) the $\overline{WP}$ pin is LOW and the nonvolatile bit WPEN is "1". This mode disables nonvolatile writes to the device's Status Register.

Setting the $\overline{WP}$ pin LOW while WPEN is a "1" while an internal write cycle to the Status Register is in progress will not stop this write operation, but the operation disables subsequent write attempts to the Status Register.
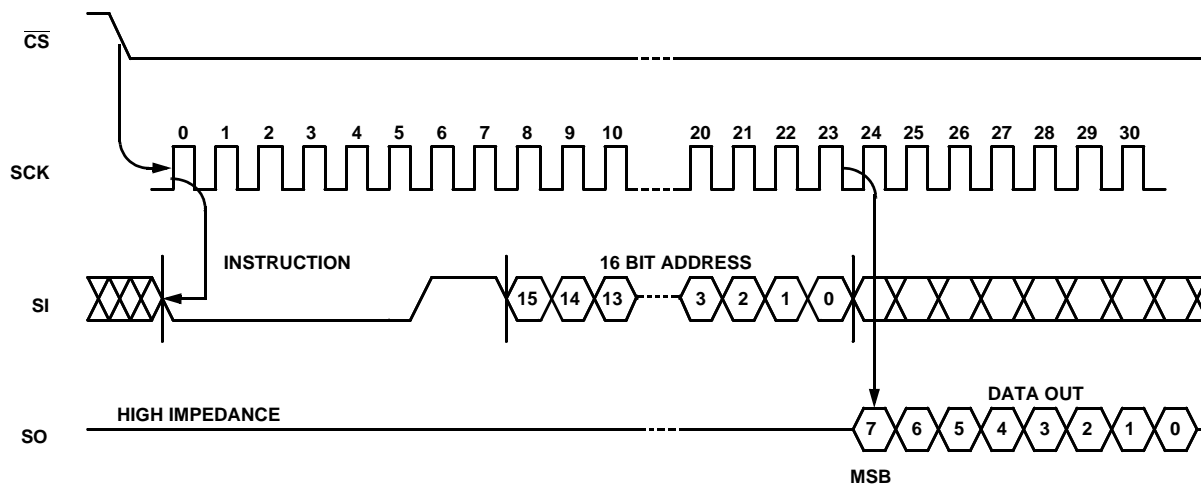

FIGURE 5. READ EEPROM ARRAY SEQUENCE

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When $\overline{WP}$ is HIGH, all functions, including nonvolatile writes to the Status Register operate normally. Setting the WPEN bit in the Status Register to "0" blocks the $\overline{WP}$ pin function, allowing writes to the Status Register when $\overline{WP}$ is HIGH or LOW. Setting the WPEN bit to "1" while the $\overline{WP}$ pin is LOW activates the Programmable ROM mode, thus requiring a change in the $\overline{WP}$ pin prior to subsequent Status Register changes. This allows manufacturing to install the device in a system with $\overline{WP}$ pin grounded and still be able to program the Status Register. Manufacturing can then load Configuration data, manufacturing time and other parameters into the EEPROM, then set the portion of memory to be protected by setting the block lock bits, and finally set the "OTP mode" by setting the WPEN bit. Data changes now require a hardware change.

Read Sequence

When reading from the EEPROM memory array, $\overline{CS}$ is first pulled low to select the device. The 8-bit READ instruction is transmitted to the device, followed by the 16-bit address. After the READ opcode and address are sent, the data stored in the memory at the selected address is shifted out on the SO line. The data stored in memory at the next address can be read sequentially by continuing to provide clock pulses. The address is automatically incremented to the next higher address after each byte of data is shifted out. When the highest address is reached, the address counter rolls over to address $0000 allowing the read cycle to be continued indefinitely. The read operation is terminated by taking $\overline{CS}$ high. Refer to the Read EEPROM Array Sequence (Figure 5).

To read the Status Register, the $\overline{CS}$ line is first pulled low to select the device followed by the 8-bit RDSR instruction. After the RDSR opcode is sent, the contents of the Status Register are shifted out on the SO line. Refer to the Read Status Register Sequence (Figure 6).

Write Sequence

Prior to any attempt to write data into the device, the "Write Enable" Latch (WEL) must first be set by issuing the WREN instruction (Figure 7). $\overline{CS}$ is first taken LOW, then the WREN instruction is clocked into the device. After all eight bits of the instruction are transmitted, $\overline{CS}$ must then be taken HIGH. If the user continues the Write Operation without taking $\overline{CS}$ HIGH after issuing the WREN instruction, the Write Operation will be ignored.

To write data to the EEPROM memory array, the user then issues the WRITE instruction followed by the 16 bit address and then the data to be written. Any unused address bits are specified to be "0's". The WRITE operation minimally takes 32 clocks. $\overline{CS}$ must go low and remain low for the duration of the operation. If the address counter reaches the end of a page and the clock continues, the counter will roll back to the first address of the page and overwrite any data that may have been previously written.

For the Page Write Operation (byte or page write) to be completed, $\overline{CS}$ can only be brought HIGH after bit 0 of the last data byte to be written is clocked in. If it is brought HIGH at any other time, the write operation will not be completed (Figure 8).

To write to the Status Register, the WRSR instruction is followed by the data to be written (Figure 9). Data bits 0 and 1 must be "0".

While the write is in progress following a Status Register or EEPROM Sequence, the Status Register may be read to check the WIP bit. During this time the WIP bit will be high.

Operational Notes

The device powers-up in the following state:

- The device is in the low power standby state.
- A HIGH to LOW transition on $\overline{CS}$ is required to enter an active state and receive an instruction.
- SO pin is high impedance.
- The Write Enable Latch is reset.
- The Flag Bit is reset.
- Reset Signal is active for t_{PURST}.

Data Protection

The following circuitry has been included to prevent inadvertent writes:

- A WREN instruction must be issued to set the Write Enable Latch.
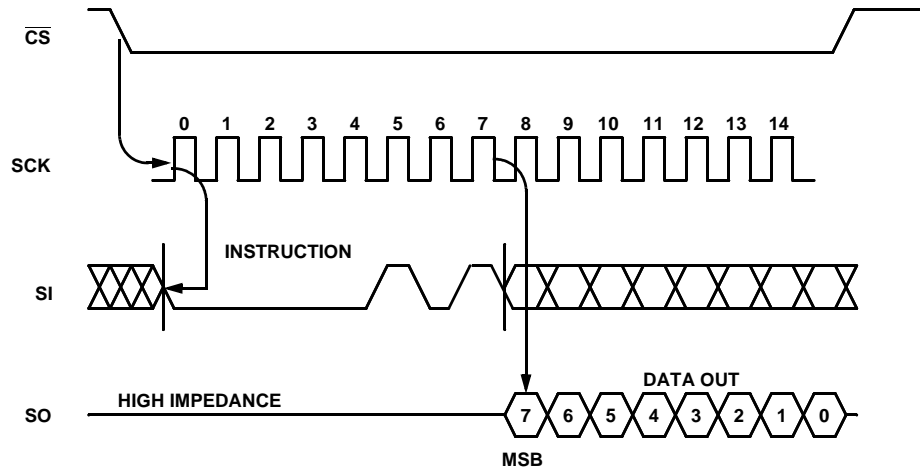- $\overline{CS}$ must come HIGH at the proper clock count in order to start a nonvolatile write cycle.

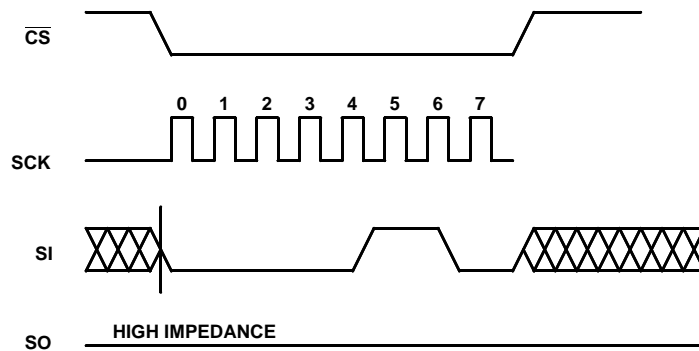**FIGURE 6. READ STATUS REGISTER SEQUENCE**
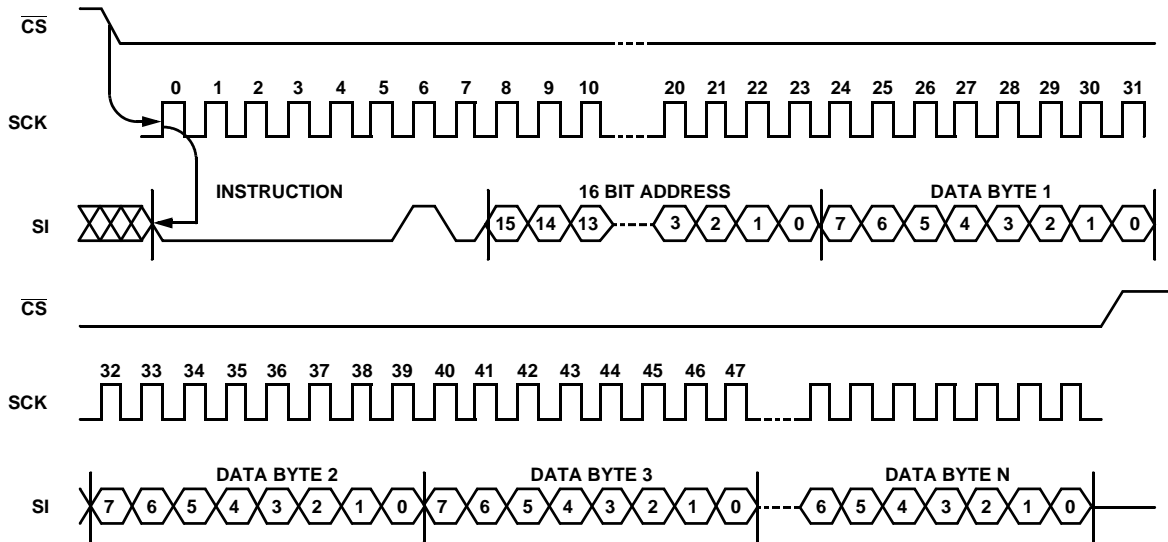

FIGURE 7. WRITE ENABLE LATCH SEQUENCE

FIGURE 8. WRITE SEQUENCE
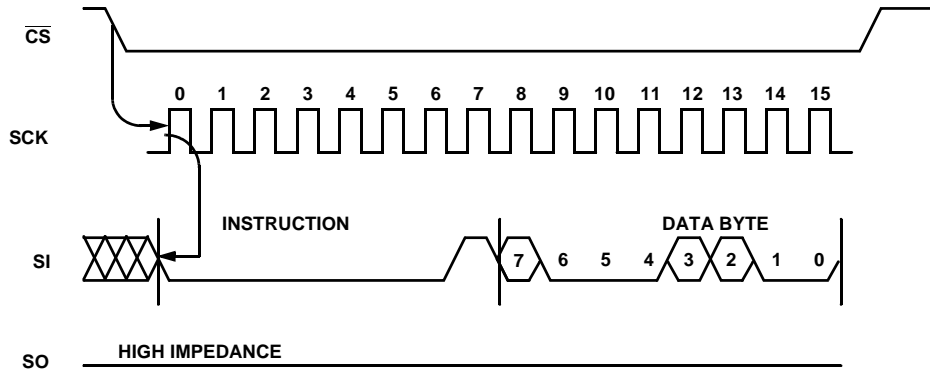
FIGURE 9. STATUS REGISTER WRITE SEQUENCE

Symbol Table

WAVEFORM	INPUTS	OUTPUTS
	MUST BE STEADY	WILL BE STEADY
	MAY CHANGE FROM LOW TO HIGH	WILL CHANGE FROM LOW TO HIGH
	MAY CHANGE FROM HIGH TO LOW	WILL CHANGE FROM HIGH TO LOW
	DON'T CARE: CHANGES ALLOWED	CHANGING: STATE NOT KNOWN
	N/A	CENTER LINE IS HIGH IMPEDANCE

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Absolute Maximum Ratings

Temperature under bias . . . . -65 to +135°C
Storage temperature . . . . -65 to +150°C
Voltage on any pin with
  respect to V_{SS} . . . . -1.0V to +7V
D.C. output current 5mA
Lead temperature (soldering, 10 seconds) . . . . 300°C

Recommended Operating Conditions

Temperature . . . . -40°C to +85°C
Supply Voltage . . . . 2.7V to 5.5V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Operating Specifications   Over operating conditions unless otherwise specified.

SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
				LIMITS		
I_{CC1}	V_{CC} Write Current (Active)	SCK = V_{CC} x 0.1/V_{CC} x 0.9 @ 2MHz, SO = Open			5	mA
I_{CC2}	V_{CC} Read Current (Active)	SCK = V_{CC} x 0.1/V_{CC} x 0.9 @ 2MHz, SO = Open			0.4	mA
I_{SB1}	V_{CC} Standby Current WDT = OFF	$\overline{CS}$ = V_{CC}, V_{IN} = V_{SS} or V_{CC}, V_{CC} = 5.5V			1	µA
I_{SB2}	V_{CC} Standby Current WDT = ON	$\overline{CS}$ = V_{CC}, V_{IN} = V_{SS} or V_{CC}, V_{CC} = 5.5V			50	µA
I_{SB3}	V_{CC} Standby Current WDT = ON	$\overline{CS}$ = V_{CC}, V_{IN} = V_{SS} or V_{CC}, V_{CC} = 3.6V			20	µA
I_{LI}	Input Leakage Current	V_{IN} = V_{SS} to V_{CC}		0.1	10	µA
I_{LO}	Output Leakage Current	V_{OUT} = V_{SS} to V_{CC}		0.1	10	µA
V_{IL}[1]	Input LOW Voltage		-0.5		V_{CC} x 0.3	V
V_{IH}[1]	Input HIGH Voltage		V_{CC} x 0.7		V_{CC} + 0.5	V
V_{OL1}	Output LOW Voltage	V_{CC} > 3.3V, I_{OL} = 2.1mA			0.4	V
V_{OL2}	Output LOW Voltage	2V < V_{CC} ≤ 3.3V, I_{OL} = 1mA			0.4	V
V_{OL3}	Output LOW Voltage	V_{CC} ≤ 2V, I_{OL} = 0.5mA			0.4	V
V_{OH1}	Output HIGH Voltage	V_{CC} > 3.3V, I_{OH} = −1.0mA	V_{CC} - 0.8			V
V_{OH2}	Output HIGH Voltage	2V < V_{CC} ≤ 3.3V, I_{OH} = −0.4mA	V_{CC} - 0.4			V
V_{OH3}	Output HIGH Voltage	V_{CC} ≤ 2V, I_{OH} = −0.25mA	V_{CC} - 0.2			V
V_{OLS}	Reset Output LOW Voltage	I_{OL} = 1mA			0.4	V

Capacitance T_A = +25°C, f = 1MHz, V_{CC} = 5V

SYMBOL	TEST	MAX.	UNIT	CONDITIONS
C_{OUT}[2]	Output Capacitance (SO, $\overline{RESET}$, RESET)	8	pF	V_{OUT} = 0V
C_{IN}[2]	Input Capacitance (SCK, SI, $\overline{CS}$, $\overline{WP}$)	6	pF	V_{IN} = 0V

NOTES:

1. V_{IL} min. and V_{IH} max. are for reference only and are not tested.

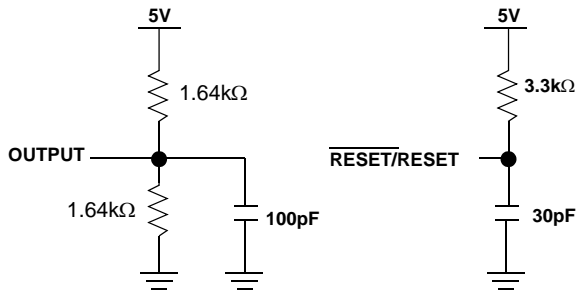2. This parameter is periodically sampled and not 100% tested.

FIGURE 10. EQUIVALENT A.C. LOAD CIRCUIT AT 5V V$_{CC}$

A.C. Test Conditions

|	
Input pulse levels	V$_{CC}$ x 0.1 to V$_{CC}$ x 0.9
Input rise and fall times	10ns
Input and output timing level	V$_{CC}$ x0.5

AC Electrical Specifications Serial Input Timing (Over operating conditions unless otherwise specified.)

SYMBOL	PARAMETER	2.7-5.5V		UNIT
		MIN	MAX	
f$_{SCK}$	Clock Frequency	0	2	MHz
t$_{CYC}$	Cycle Time	500		ns
t$_{LEAD}$	$\overline{CS}$ Lead Time	250		ns
t$_{LAG}$	$\overline{CS}$ Lag Time	250		ns
t$_{WH}$	Clock HIGH Time	200		ns
t$_{WL}$	Clock LOW Time	200		ns
t$_{SU}$	Data Setup Time	50		ns
t$_{H}$	Data Hold Time	50		ns
t$_{RI}$[3]	Input Rise Time		100	ns
t$_{FI}$[3]	Input Fall Time		100	ns
t$_{CS}$	$\overline{CS}$ Deselect Time	500		ns
t$_{WC}$[4]	Write Cycle Time		10	ms
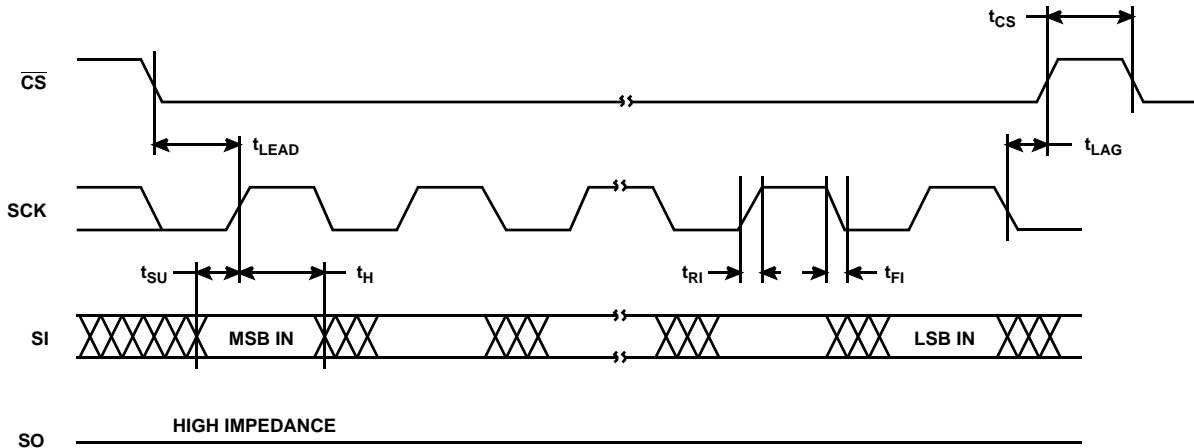
FIGURE 11. SERIAL INPUT TIMING

AC Electrical Specifications   Serial Output Timing(Over operating conditions unless otherwise specified.)

SYMBOL	PARAMETER	2.7-5.5V		UNIT
		MIN	MAX	
f_{SCK}	Clock Frequency	0	2	MHz
t_{DIS}	Output Disable Time		250	ns
t_V	Output Valid from Clock Low		200	ns
t_{HO}	Output Hold Time	0		ns
t_{RO}[3]	Output Rise Time		100	ns
t_{FO}[3]	Output Fall Time		100	ns

NOTES:

3. This parameter is periodically sampled and not 100% tested.

4. t_{WC} is the time from the rising edge of $\overline{CS}$ after a valid write sequence has been sent to the end of the self-timed internal nonvolatile write cycle.
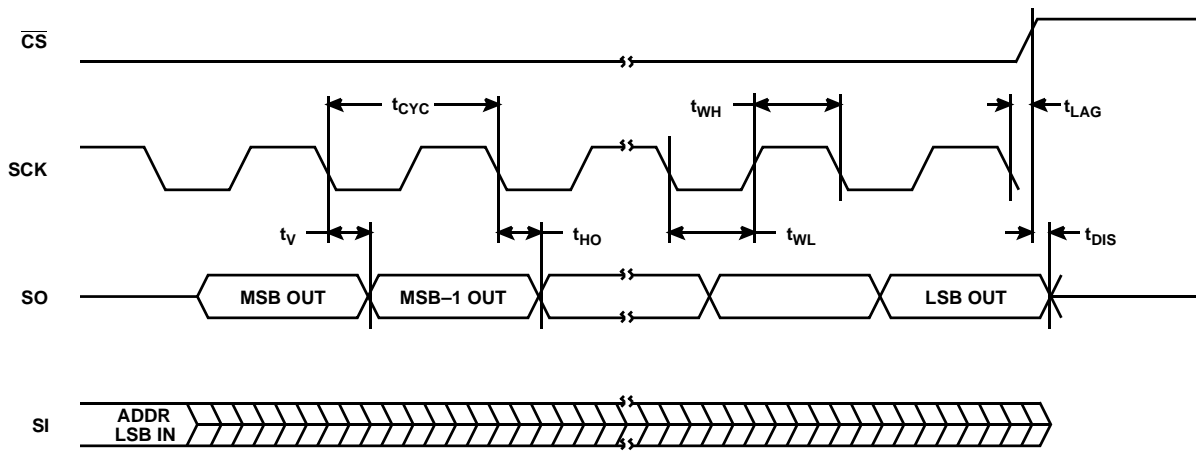
TABLE 3. SERIAL OUTPUT TIMING
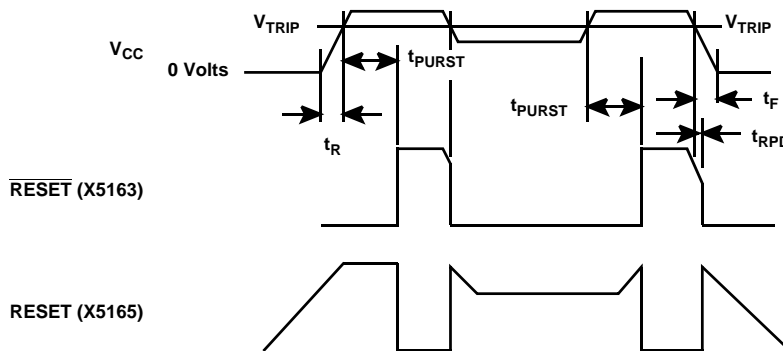
TABLE 4. POWER-UP AND POWER-DOWN TIMING

RESET Output Timing

SYMBOL	PARAMETER	MIN	TYP	MAX	UNIT
V_{TRIP}	Reset Trip Point Voltage, X5163-4.5A, X5163-4.5A Reset Trip Point Voltage, X5163, X5165 Reset Trip Point Voltage, X5163-2.7A, X5165-2.7A Reset Trip Point Voltage, X5163-2.7, X5165-2.7	4.5 4.25 2.85 2.55	4.63 4.38 2.92 2.63	4.75 4.5 3.0 2.7	V
V_{TH}	V_{TRIP} Hysteresis (HIGH to LOW vs. LOW to HIGH V_{TRIP} voltage)		20		mV
t_{PURST}	Power-up Reset Time Out	100	200	280	ms
t_{RPD}[5]	V_{CC} Detect to Reset/Output			500	ns
t_F[5]	V_{CC} Fall Time	100			μs
t_R[5]	V_{CC} Rise Time	100			μs
V_{RVALID}	Reset Valid V_{CC}	1			V

NOTES:

5. This parameter is periodically sampled and not 100% tested.

6. Typical values not tested.
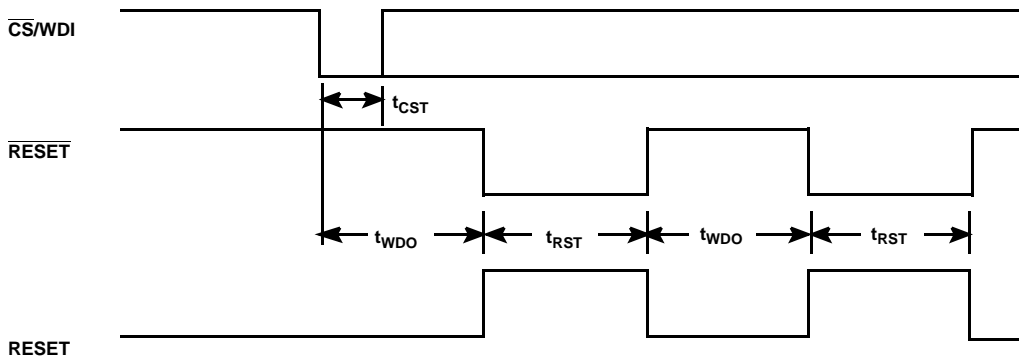
FIGURE 12. $\overline{CS}$/WDI VS. RESET/$\overline{RESET}$ TIMING

RESET/$\overline{RESET}$ Output Timing

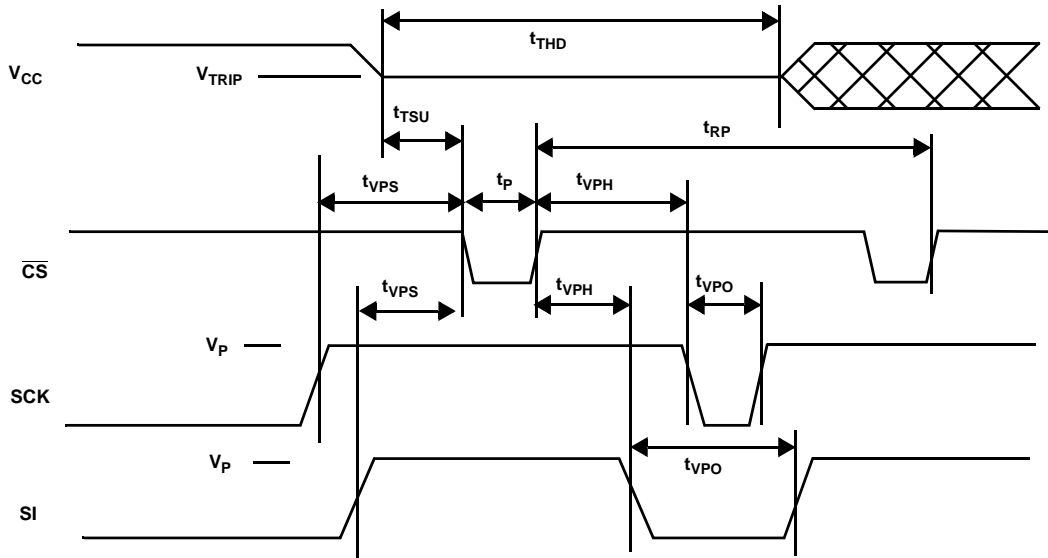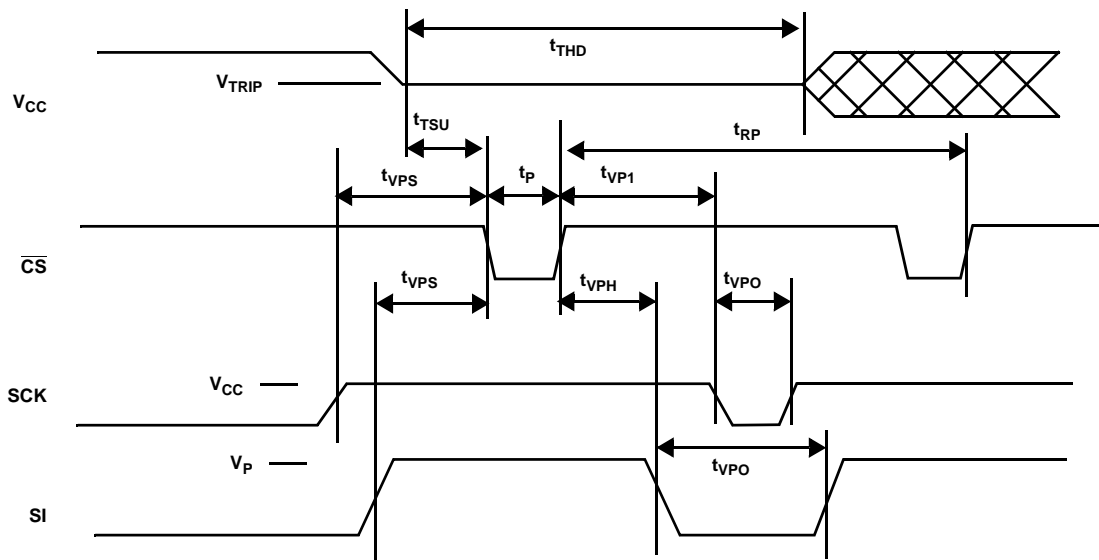| SYMBOL	PARAMETER	MIN	TYP	MAX	UNIT

t_{WDO}	Watchdog Time Out Period,
	    WD1 = 1, WD0 = 0
	    WD1 = 0, WD0 = 1
	    WD1 = 0, WD0 = 0
		100
		450
		1
			200
			600
			1.4
				300
				800
				2
					ms
					ms
					sec

t_{CST}	$\overline{CS}$ Pulse Width to Reset the Watchdog	400			ns
t_{RST}	Reset Time Out	100	200	300	ms

FIGURE 13. V$_{TRIP}$ SET CONDITIONS

FIGURE 14. V$_{TRIP}$ RESET CONDITIONS

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V_{TRIP} Programming Specifications: V_{CC} = 1.7-5.5V; Temperature = 0°C to 70°C

PARAMETER	DESCRIPTION	MIN	MAX	UNIT
t_{VPS}	SCK V_{TRIP} Program Voltage Setup time	1		µs
t_{VPH}	SCK V_{TRIP} Program Voltage Hold time	1		µs
t_P	V_{TRIP} Program Pulse Width	1		µs
t_{TSU}	V_{TRIP} Level Setup time	10		µs
t_{THD}	V_{TRIP} Level Hold (stable) time	10		ms
t_{WC}	V_{TRIP} Write Cycle Time		10	ms
t_{RP}	V_{TRIP} Program Cycle Recovery Period (Between successive programming cycles)	10		ms
t_{VPO}	SCK V_{TRIP} Program Voltage Off time before next cycle	0		ms
V_P	Programming Voltage	15	18	V
V_{TRAN}	V_{TRIP} Programed Voltage Range	1.7	5.0	V
V_{ta1}	Initial V_{TRIP} Program Voltage accuracy (V_{CC} applied-V_{TRIP}) (Programmed at 25°C.)	-0.1	+0.4	V
V_{ta2}	Subsequent V_{TRIP} Program Voltage accuracy [(V_{CC} applied-V_{ta1})-V_{TRIP}] (Programmed at 25°C.)	-25	+25	mV
V_{tr}	V_{TRIP} Program Voltage repeatability (Successive program operations.) (Programmed at 25°C.)	-25	+25	mV
V_{tv}	V_{TRIP} Program variation after programming (0-75°C). (Programmed at 25°C.)	-25	+25	mV

V_{TRIP} programming parameters are periodically sampled and are not 100% tested.
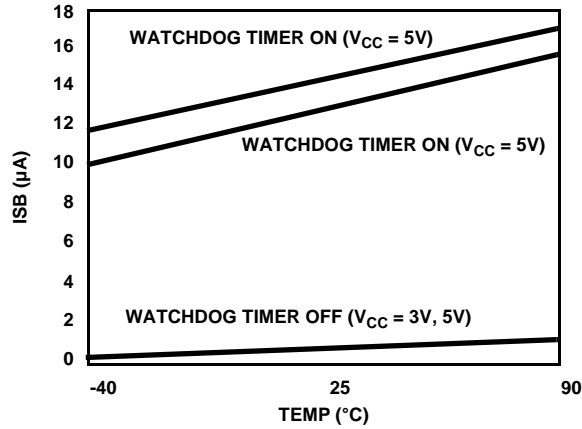
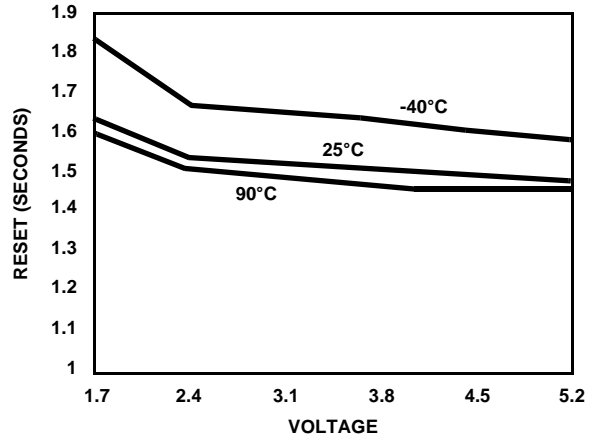FIGURE 15. V_{CC} SUPPLY CURRENT VS. TEMPERATURE (I_{SB})

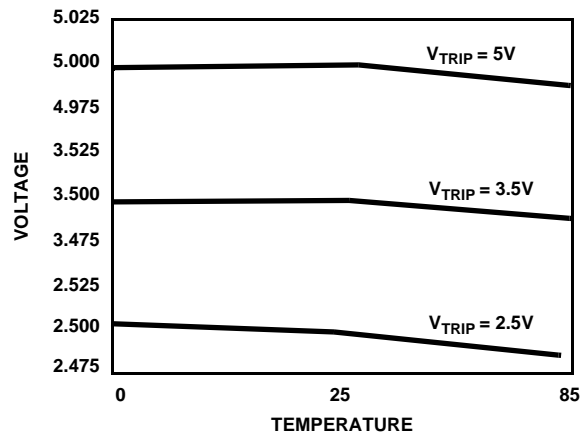FIGURE 16. t_{WDO} VS. VOLTAGE/TEMPERATURE (WD1, 0 = 1, 1)

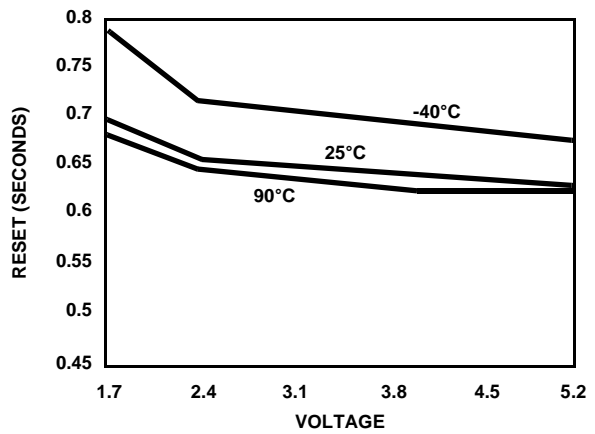FIGURE 17. V_{TRIP} vs. Temperature (programmed at 25°C)

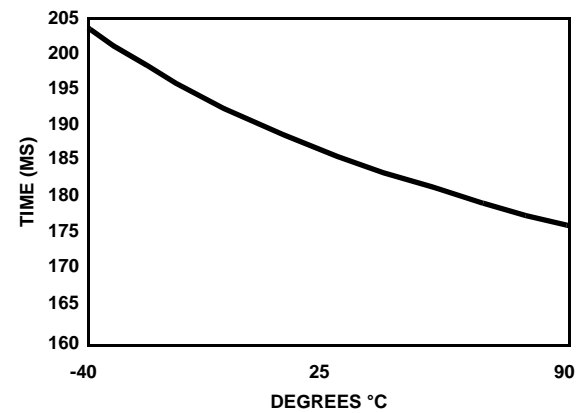FIGURE 18. t_{WDO} VS. VOLTAGE/TEMPERATURE (WD1, 0 = 1, 0)
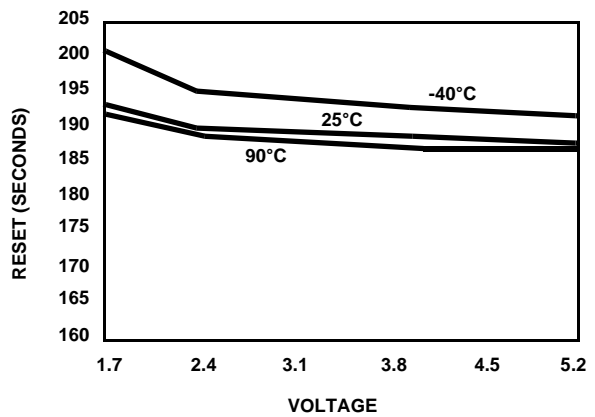

FIGURE 19. t_{PURST} VS. TEMPERATURE

FIGURE 20. t_{WDO} VS. VOLTAGE/TEMPERATURE (WD1, 0 0 = 0, 1)

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Packaging Information

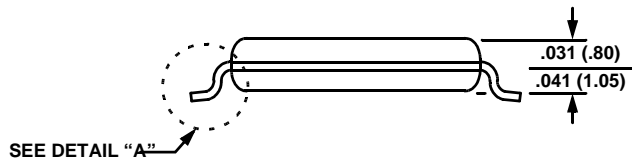**8-LEAD PLASTIC SMALL OUTLINE GULL WING PACKAGE TYPE S**

PIN 1 INDEX →

PIN 1

0.150 (3.80) / 0.158 (4.00)

0.228 (5.80) / 0.244 (6.20)

0.014 (0.35) / 0.019 (0.49)

0.188 (4.78) / 0.197 (5.00)

(4X) 7°

0.053 (1.35) / 0.069 (1.75)

0.004 (0.19) / 0.010 (0.25)

0.050 (1.27)

0.010 (0.25) / 0.020 (0.50) X 45°

0° - 8°

0.0075 (0.19) / 0.010 (0.25)

0.016 (0.410) / 0.037 (0.937)

0.050" TYPICAL

0.050" TYPICAL

0.250"

0.030" TYPICAL 8 PLACES

FOOTPRINT
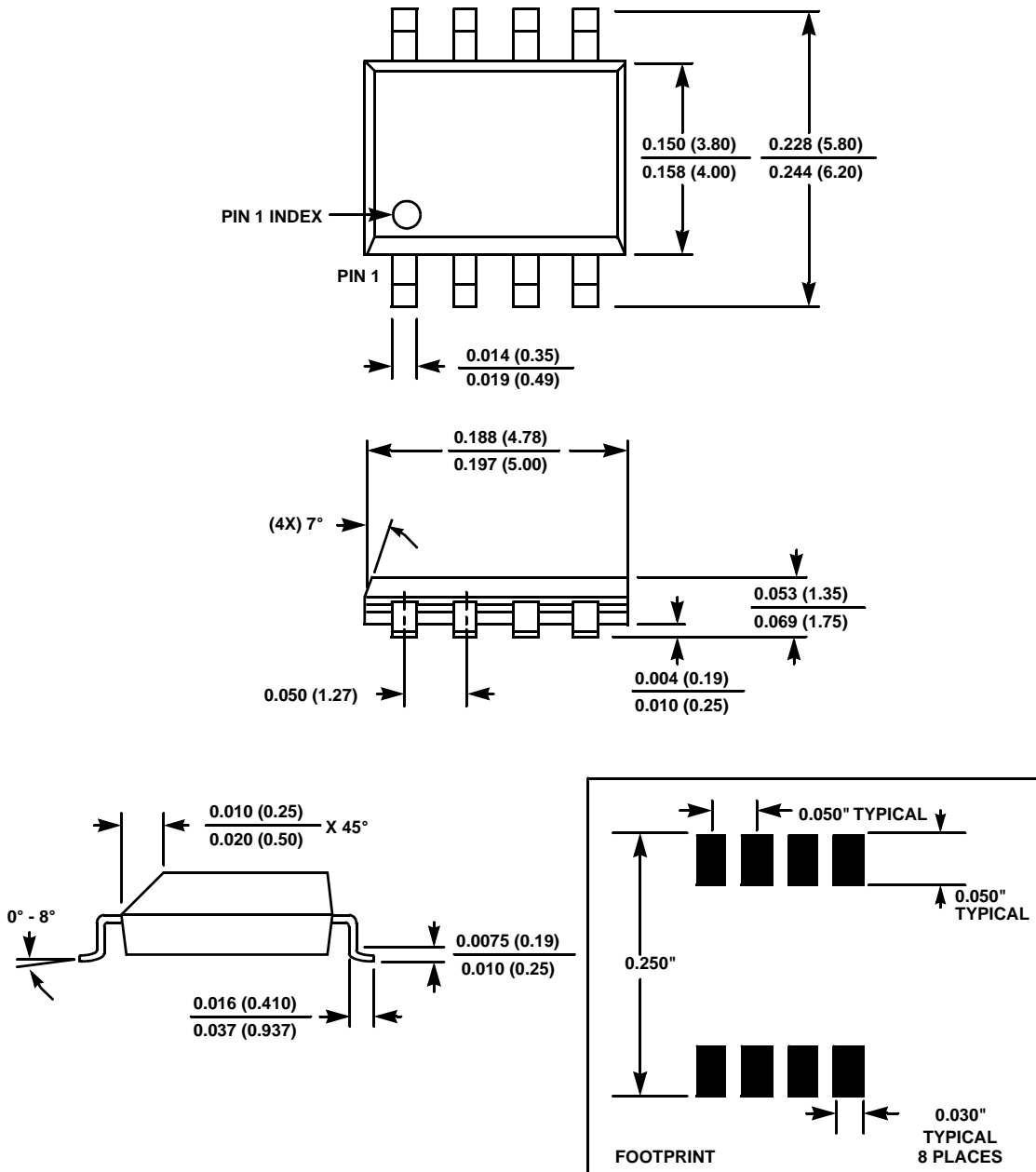
NOTE: ALL DIMENSIONS IN INCHES (IN PARENTHESES IN MILLIMETERS)

Packaging Information

14-LEAD PLASTIC, TSSOP, PACKAGE TYPE V
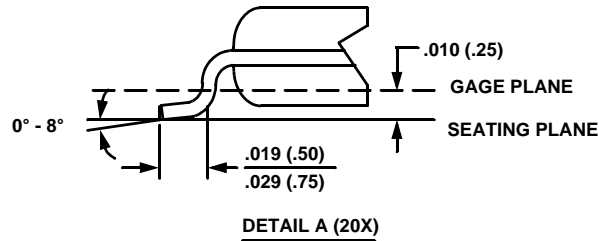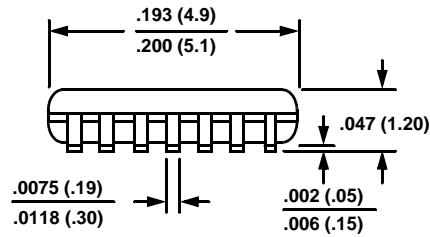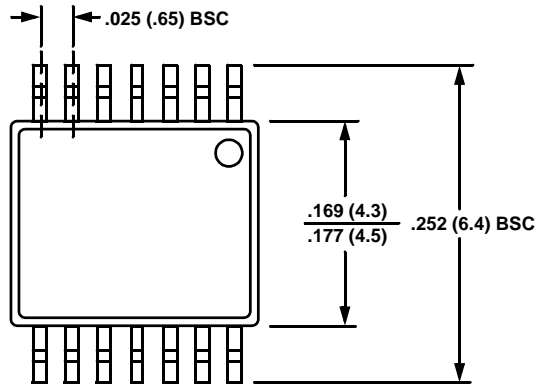
.025 (.65) BSC

$\dfrac{.169\ (4.3)}{.177\ (4.5)}$ .252 (6.4) BSC

$\dfrac{.193\ (4.9)}{.200\ (5.1)}$

.047 (1.20)

$\dfrac{.0075\ (.19)}{.0118\ (.30)}$

$\dfrac{.002\ (.05)}{.006\ (.15)}$

.010 (.25)

GAGE PLANE

SEATING PLANE

0° - 8°

$\dfrac{.019\ (.50)}{.029\ (.75)}$

DETAIL A (20X)

$\dfrac{.031\ (.80)}{.041\ (1.05)}$

SEE DETAIL "A"

NOTE: ALL DIMENSIONS IN INCHES (IN PARENTHESES IN MILLIMETERS)

Ordering Information

V_{CC} RANGE	V_{TRIP} RANGE	PACKAGE	OPERATING TEMPERATURE RANGE	PART NUMBER RESET (ACTIVE LOW)	PART NUMBER RESET (ACTIVE HIGH)
4.5-5.5V	4.5.4.75	8-Pin PDIP	0°C - 70°C	X5163P-4.5A	
			-40°C - 85°C	X5163PI-4.5A	X5165PI-4.5A
		8L SOIC	0°C - 70°C	X5163S8-4.5A	X5165S8-4.5A
			-40°C - 85°C	X5163S8I-4.5A	X5165S8I-4.5A
		14L TSSOP	0°C - 70°C	X5163V14-4.5A	X5165V14-4.5A
			-40°C - 85°C	X5163V14I-4.5A	X5165V14I-4.5A
4.5-5.5V	4.25.4.5	8-Pin PDIP	0°C - 70°C	X5163P	X5165P
			-40°C - 85°C	X5163PI	X5165PI
		8L SOIC	0°C - 70°C	X5163S8	X5165S8
			0°C - 70°C	X51638S8	
			0°C - 70°C	X5163S8T1	X5165S8T1
			0°C - 70°C	X5163S8T2	
			-40°C - 85°C	X5163S8I	X5165S8I
			-40°C - 85°C	X5163S8IT1	X5165S8IT1
		14L TSSOP	0°C - 70°C	X5163V14	X5165V14
			0°C - 70°C	X5163V14T1	X5165V14T1
			-40°C - 85°C	X5163V14I	X5165V14I
			-40°C - 85°C	X5163V14IT1	X5165V14IT1
2.7-5.5V	2.85-3.0	8-Pin PDIP	0°C - 70°C	X5163P-2.7A	X5165P-2.7A
			-40°C - 85°C	X5163PI-2.7A	X5165PI-2.7A
		8L SOIC	0°C - 70°C	X5163S8-2.7A	X5165S8-2.7A
			0°C - 70°C	X5163S8-2.7AT1	
			-40°C - 85°C	X5163S8I-2.7A	X5165S8I-2.7A
			-40°C - 85°C	X5163S8I-2.7AT1	
		14L TSSOP	0°C - 70°C	X5163V14-2.7A	X5165V14-2.7A
			-40°C - 85°C	X5163V14I-2.7A	X5165V14I-2.7A
			-40°C - 85°C	X5163V14I-2.7T1	X5165V14I-2.7T1
2.7-5.5V	2.55-2.7	8-Pin PDIP	0°C - 70°C	X5163P-2.7	X5165P-2.7
			-40°C - 85°C	X5163PI-2.7	X5165PI-2.7
		8L SOIC	0°C - 70°C	X5163S8-2.7	X5165S8-2.7
			0°C - 70°C	X5163S8-2.7T1	X5165S8-2.7T1
			-40°C - 85°C	X5163S8I-2.7	X5165S8I-2.7
			-40°C - 85°C		X5165S8I-2.7T1
		14L TSSOP	0°C - 70°C	X5163V14-2.7	X5165V14-2.7
			0°C - 70°C	X5163V14-2.7T1	X5165V14-2.7T1
			-40°C - 85°C	X5163V14I-2.7	X5165V14I-2.7

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Part Mark Information

X5163, X51665

$$\begin{array}{ll} \textbf{W} \\ \textbf{X} \end{array}$$

W ——— Blank = 8-Lead SOIC
V = 14 Lead TSSOP

Blank = 5V ±10%, 0°C to +70°C, V_{TRIP} = 4.25-4.5
A = 5V±10%, 0°C to +70°C, V_{TRIP} = 4.5-4.75
I = 5V ±10%, -40°C to +85°C, V_{TRIP} = 4.25-4.5
IA = 5V ±10%, -40°C to +85°C, V_{TRIP} = 4.5-4.75
F = 2.7V to 5.5V, 0°C to +70°C, V_{TRIP} = 2.55-2.7
FA = 2.7V to 5.5V, 0°C to +70°C, V_{TRIP} = 2.85-3.0
G = 2.7V to 5.5V, -40°C to +85°C, V_{TRIP} = 2.55-2.7
GA = 2.7V to 5.5V, -40°C to +85°C, V_{TRIP} = 2.85-3.0

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